

Midium Power Transistors (-50V / -3A)

2SAR543R

Structure

PNP Silicon epitaxial planar transistor

Features

1) Low saturation voltage $V_{CE\;(sat)} = -0.4V\;(Max.)\;(I_C\;/\;I_B = -2A\;/\;-100mA)$

2) High speed switching

Applications

Driver

Packaging specifications

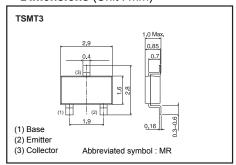
_	Package	TSMT3
	Code	TL
	Basic ordering unit (pieces)	3000

●Absolute maximum ratings (Ta=25°C)

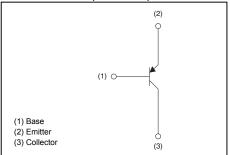
Parameter		Symbol	Limits	Unit	
Collector-base voltage		V_{CBO}	-50	V	
Collector-emitter voltage		V_{CEO}	-50	V	
Emitter-base voltage		V_{EBO}	-6	V	
Collector current	DC	Ic	-3	Α	
	Pulsed	I _{CP} *1	-6	Α	
Power dissipation		P _D *2	0.5	W	
		P _D *3	1.0	W	
Junction temperature		T _j	150	°C	
Range of storage temperature		T _{stg}	-55 to 150	°C	

^{*1} Pw=10ms, Single Pulse

• Dimensions (Unit : mm)



• Inner circuit (Unit : mm)



^{*2} Mounted on a recommended land

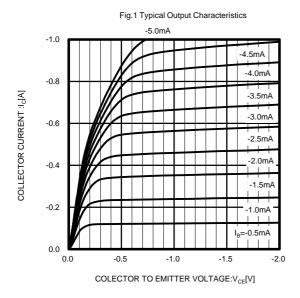
^{*3} Mounted on a ceramic substrate(40×40×0.7mm)

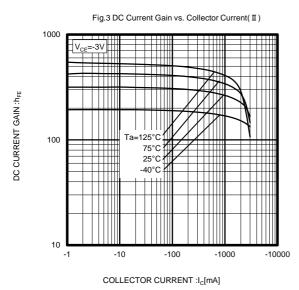
●Electrical characteristics (Ta=25°C)

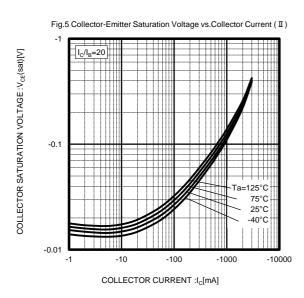
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV_{CEO}	-50	-	-	V	I _C = -1mA	
Collector-base breakdown voltage	BV_{CBO}	-50	-	-	V	I _C = -100μA	
Emitter-base breakdown voltage	BV_{EBO}	-6	-	-	V	I _E = -100μA	
Collector cut-off current	I _{CBO}	1	-	-1.0	μ A	V _{CB} = -50V	
Emitter cut-off current	I _{EBO}	1	-	-1.0	μ A	V _{EB} = -4V	
Collector-emitter staturation voltage	$V_{\text{CE(sat)}}$	1	-200	-400	mV	I _C = -2A, I _B = -100mA	
DC current gain	h _{FE}	180		450	-	V_{CE} = -3V, I_{C} = -100mA	
Transition frequency	f _T	ı	300	ı	MHz	V _{CE} = -10V I _E =300mA, f=100MHz	
Collector output capacitance	C _{ob}	-	35	-	pF	V _{CB} = -10V, I _E =0A f=1MHz	
Turn-on time	t _{on} *	-	45	-	ns	1 - 24 1 - 200m4	
Storage time	t _{stg} *	-	250	-	ns	I _C = -2A, I _{B1} = -200mA, I _{B2} =200mA, V _{CC} ~-10V	
Fall time	t _f *	-	40	_	ns	1.B2	

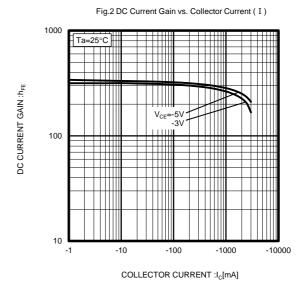
^{*} See switching time test circuit

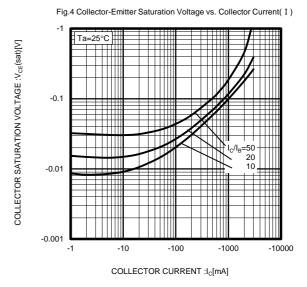
●Electrical characteristic curves (Ta=25°C)











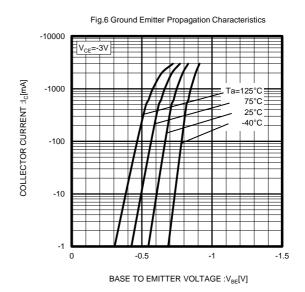


Fig.7 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs.Collector-Base Voltage

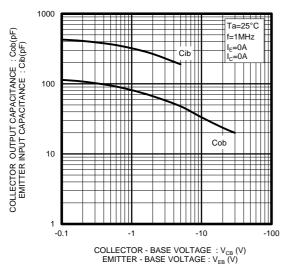
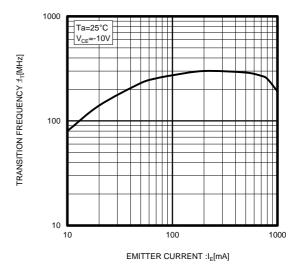
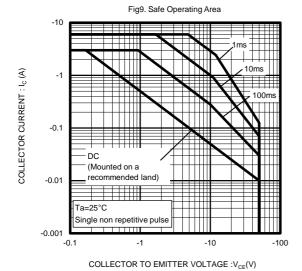
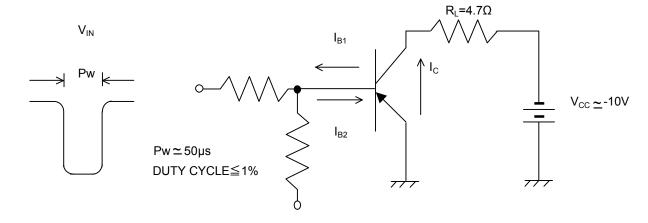


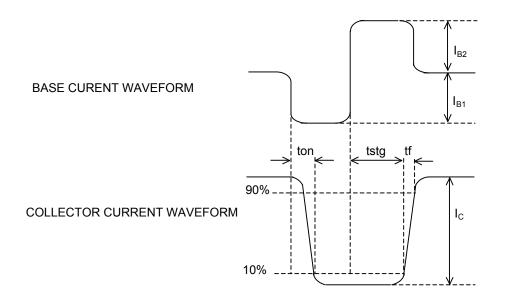
Fig8. Gain Bandwidth Product vs. Emitter Current





•Switching time test circuit





Notes

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